TC3567CFSG Bluetooth[®] low energy IC

Rev 1.1



The Bluetooth[®] word mark and logos are registered trademarks owned by the Bluetooth SIG, Inc. and any use of such marks by Toshiba is under license. Other trademarks and trade names are those of their respective owners. ARM and Cortex are registered trademarks of ARM Limited (or its subsidiaries) in the EU and/or elsewhere. All rights reserved.

Contents

1.	General	Description	4
1.1		ct Concept	
1.2		es	
2.	Pin Func	tion	5
2.1	. TC356	S7CFSG Pin Assignment (Top View)	5
2.2		nction Descriptions	
2.3	B. GPIO	function list	9
2.4	. Power	Supply Pins	10
3.	System (Configuration	11
3.1	. Block	Diagram	11
3.2	2. Boot S	Sequence	12
4.		e Interfaces	
4.1	. Reset	Interface (Power up sequence)	13
4	4.1.1.	Features	13
4	4.1.2.	Connection Example	13
4.2	. UART	Interface	14
4	1.2.1.	Features	14
4	1.2.2.	Connection Example	14
4	4.2.3.	Frame Format	15
4	1.2.4.	Flow Control Function	15
4	4.2.5.	TX message spacing function	16
4	4.2.6.	Error Detecting Functions	17
4	1.2.7.	Host Wake up Function	18
4	4.2.8.	HCI mode	18
	4.2.8.1.	HCI Reset	18
4.3	8. SPI Int	terface	19
4	4.3.1.	Features	19
4	4.3.2.	Connection Example	19
4	4.3.3.	Frame Format	20
4.4	. I ² C Inte	erface	21
4	1.4.1.	Features	21
4	1.4.2.	Connection Example	21
4	1.4.3.	Selection of External Pull-up Resistor Value	22
4	1.4.4.	Frame Format	23
4.5	5. PWM	Interface	24
4	4.5.1.	Pulse Generation Function	24
4	1.5.2.	Rhythm Function (Output Masking)	25
4.6	. ADC		26
4	1.6.1.	Features	26
4	4.6.2.	Descriptions	26
4.7	. IC Ref	erence Clock Interface	27
4	4.7.1.	Features	27
4	1.7.2.	Connection Example	27
4.8	8. Sleep	Clock Interface	28
4	1.8.1.	Sleep Clock Connection Example	28
4	1.8.2.	External Oscillator Connection Example	28
5.	Electric C	Characteristics	29

5.1.	Absolute Maximum Ratings	29
5.2.	Operating Conditions	30
5.3.	DC electric characteristics	31
5.3	3.1. Current Consumption (Design value)	31
5.4.	Built-in Regulator Characteristics	33
5.5.	ADC Characteristics	33
5.6.	RF Characteristics (Design value)	34
5.7.	AC Interface Characteristics (Design value)	36
5.7	7.1. UART Interface	36
5.7	7.2. I ² C Interface	37
5	5.7.2.1. Normal Mode	37
5	5.7.2.2. Fast mode	38
5.7	7.3. SPI Interface	39
5.8.	Characteristics of Flash-ROM block	40
6.	System Configuration Example	41
6.1.	In HCI mode	
6.2.	In User-App mode	42
7.	Package outline	43
7.1.	Outline dimensional drawing TC3567CFSG (P-VQFN40-0505-0.40-005/F01)	43
RESTR	RICTIONS ON PRODUCT USE	44

1. General Description

1.1. Product Concept

TC3567CFSG (Later omitted TC3567C.) are compliant with Bluetooth[®] core specification 4.2. RF analog parts and baseband digital parts are built in them, and TC3567C provides Bluetooth[®] HCI (Host Control Interface) functions and Bluetooth[®] low energy GATT profile functions defined by Bluetooth[®] core specifications. Additionally, this IC works as an application using low power Bluetooth[®] communication by storing the application program into built-in flash ROM.

1.2. Features

- > Compliant with Bluetooth® Ver4.2 low energy
 - ♦ Built-in Bluetooth[®] Baseband
 - ♦ Built-in Bluetooth[®]RF analog
 - ♦ Built-in ARM® Cortex®-M0 (13 MHz or 26 MHz function mode is able to select to run)
 - ♦ On-chip mask ROM for Bluetooth® program (216 KB)
 - ♦ On-chip work RAM for Bluetooth[®] Baseband process (128 KB)
 - ♦ On-chip NOR Flash Memory (128 KB, More than 100,000 erase and program cycles)
 - Supports patch program loader function
 - ♦ 2 boot modes (HCI mode, User-App mode)
- General Purpose IO (17 ports)
- General Purpose Serial Interfaces
 - ♦ SPI interface (1 ch assigned to a General Purpose IO)
 - ♦ I²C interface (1 ch assigned to a General Purpose IO)
- Host CPU Interface
 - ♦ UART interface (9600 bps to 921.6 kbps, 1ch shared with GPIOs)
 - ♦ SPI interface
- Emulator debug control interface
 - ♦ SWD(Serial Wire Debug)2-wire (1 ch)
- Wake-up Interface (2 ch assigned to a General Purpose IO)
 - Wake-up input function from sleep and deep sleep
- PWM Interface (4 ch assigned to General Purpose IOs)
- Reference Clock Input (26 MHz)
 - ♦ Built-in oscillator for crystal oscillator connection
- Sleep Clock Input (32.768 kHz)
 - ♦ External oscillator input supported
 - ♦ Built-in oscillator for crystal oscillator connection
- Works as Standalone (In User-App mode, operating by standalone is possible)
- Sleep and Deep Sleep Functions
- > Built-in DCDC converter and LDO
 - Wide range of input power supply voltages supported (Booting power supply voltage : 2.0 to 3.6 V, low battery voltage detection)
- Built-in general purpose ADC

 - ♦ Internal VDD monitoring (1 ch connected inside)
- Package:
 - ♦ TC3567CFSG: QFN Package [40 pin, 5 x5 mm, 0.4 mm pitch, 0.9 mm thickness]

2. Pin Function

2.1. TC3567CFSG Pin Assignment (Top View)

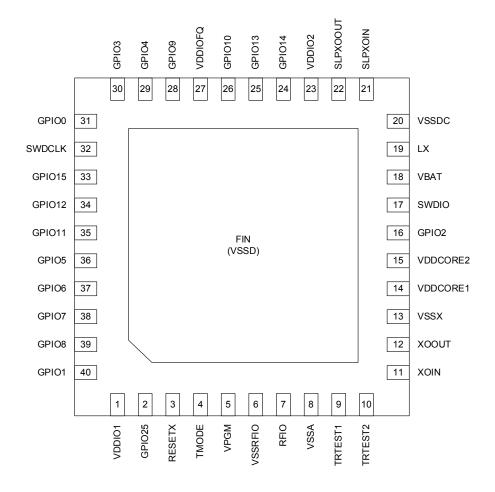


Figure 2-1 Pin Assignment (Top View)

2.2. Pin Function Descriptions

Table 2-1 shows attributes, input/output states for operating modes and descriptions for pin functions. Table 2-3 shows descriptions about power supply pins.

Table 2-1 Pin Functions

Pin name	Pin No.	Attribute	Condition	Functional description
		VDD category	Default	
		Direction	(during reset)	
		Туре		
	·		Reset interface	
RESETX	3	VDDIO	_	Hardware reset input pin.
		IN		Setting this pin to Low level put the system at reset
		Schmitt trigger		state.
			Clock interface	·
XOIN	11	VDDCORE	IN	Reference clock input pin. Please use oscillator with
		IN		26 MHz and < 50 ppm accuracy.
		OSC		A feedback resistor is built in between XOIN pin and
				XOOUT pin and a capacity array which can set
				parameters in the crystal oscillation circuit is built-in,
				so that external feedback resistances and
				capacities are unnecessary.
XOOUT	12	VDDCORE	OUT	Oscillator output for Baseband and RF reference
		OUT		clock (26 MHz) pin.
		OSC		A feedback resistor is built in between XOIN pin and
				XOOUT pin and a capacity array which can set
				parameters in the crystal oscillation circuit is built-in,
				so that external feedback resistances and
				capacities are unnecessary.
SLPXOIN	21	VDDIO	IN	Sleep clock input pin from oscillator. Please use an
		IN		oscillator with 32.768 kHz and < 500 ppm accuracy.
		OSC		A feedback resistor is built in between SLPXOIN pin
				and SLPXOOUT pin and a capacity array which
				can set parameters in the crystal oscillation circuit is
				built-in, so that external feedback resistances and
				capacities are unnecessary. An external clock can
				be input from this pin. When the crystal oscillator is
				not used and do not supply a clock from the
				outside, this pin should be connected to the GND.
SLPXOOUT	22	VDDIO	IN	Oscillator output (feedback) pin for the oscillation of
		IN/OUT		32.768 kHz.
		osc		A feedback resistor is built in between SLPXOIN pin
				and SLPXOOUT pin and a capacity array which
				can set parameters in the crystal oscillation circuit is
				built-in, so that external feedback resistances and
				capacities are unnecessary.
				When the crystal oscillator is not used, this pin
				should be connected to the GND.



Pin name	Pin No.	Attribute	Condition	Functional description
		VDD category	Default	
		Direction	(during reset)	
		Туре		
	<u>'</u>		RF interface	
RFIO	7	VDDCORE	_	RF I/O pins.
		IN/OUT		This product incorporates the 50 Ω matching circuit,
		Analog		so that external matching circuit is unnecessary.
				The RF output pattern should wire with the 50 Ω
				transmission line.
				For details, refer to the hardware application note of
				this product.
			General purpose I/O por	t
GPIO0	31	VDDIO	Refer to Table 2-2	General purpose I/O pin.
GPIO15	33	IN/OUT		During reset, the input will be disable state with
		Pull-up		disconnecting the Pull-up/Pull-down resistor.
		Pull-down		After the pin configuration by software processing, it
		Schmitt trigger		works as a GPIO pin of the input and output or
				function pin.
				Please refer to Table 2-2.
GPIO1	40	VDDIO	Refer to Table 2-2	General purpose I/O pin.
GPIO2	16	IN/OUT		During reset, the input will be disable state with
GPIO5	36	Pull-up		connecting the Pull-up resistor.
GPIO6	37	Pull-down		After the pin configuration by software processing, it
GPIO7	38	Schmitt trigger		works as a GPIO pin of the input and output or
GPIO8	39			function pin.
GPIO11	35			Please refer to Table 2-2.
GPIO12	34			In addition, GPIO1 and GPIO2 pin is used in the
GPIO25	2			case of switching operation modes.
GPIO3	30	VDDIO	Refer to Table 2-2	ADC input and general purpose I/O pin.
GPIO4	29	IN/OUT	TOTAL TABLE 2	During reset, the input will be disable state with
GPIO9	28	Pull-up		disconnecting the Pull-up/Pull-down resistor.
GPIO10	26	Pull-down		After the pin configuration by software processing, it
GPIO14	24	Schmitt trigger		works as a GPIO pin of the input and output or
		35		function pin or general purpose ADC channel pin.
				Please refer to Table 2-2.
GPIO13	25	VDDIO	Refer to Table 2-2	General purpose IO pin.
		IN/OUT		During reset, the input will be disable state with
		Pull-up		connecting the Pull-up resistor.
		Pull-down		After the pin configuration by software processing, it
		Schmitt trigger		works as a GPIO pin of the input and output or
				function pin.
				Please refer to Table 2-2.

TOSHIBA

Pin name	Pin No.	Attribute	Condition	Functional description
		VDD category	Default	
		Direction	(during reset)	
		Туре		
SWDCLK	32	VDDIO	Pull-down	Serial Wire debugger clock pin.
		IN		During the reset, it remains in the input disable state
		Pull-up		with connecting the Pull-down resistor. After the
		Pull-down		reset is released, it will be the input of the Serial
		Schmitt trigger		Wire Debugger clock.
				When not used, this pin should be open.
SWDIO	17	VDDIO	Pull-up	Serial Wire Debugger data pin and operation
		IN/OUT		switching pin.
		Pull-up		During the reset, it remains in the input disable state
		Pull-down		with connecting the Pull-up resistor. After the reset
		Schmitt trigger		is released, it will be the input and output of the
				Serial Wire Debugger data.
				In addition, SWDIO pin is used in the case of
				switching operation modes.
				When not used, this pin should be open.
			IC test interface	
TMODE	4	VDDIO	_	Test mode setting pins.
		IN		This pin is used for IC manufacturing test and need
		Schmitt trigger		to be connected to GND when assembled on a
				board.
TRTEST1	9	VDD12A	_	Analog test pins.
TRTEST2	10	IN/OUT		These pins are used for IC manufacturing test and
		Analog		need to be connected to GND when assembled on
				a board.



2.3. GPIO function list

GPIO pins can be assigned to UART I/Fs, serial memory I/Fs and etc. by TC3567C firmware or command from external Hosts. Table 2-2 shows available functions, during reset status and software controlling after reset release for each GPIO pin. About what function name shown in Table 2-2 is assigned to a plurality of pins in the same, please note that it cannot be assigned to select a plurality of pins at the same time.

Table 2-2 Available functions for GPIO

	Table 2-2 Available functions for GFIO								
Pin	During reset status	After reset release	Function 1	Function 2	Function 3	Function 4	Analog input	Pin state at unused	
GPIO0	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	WakeUp0 Input	_	_	_	_	Open	
GPIO1	Disable/ Pull-up	Input/ Pull-up (Note2)	PWM0 Output	_	_	_	_	Open (Note1)	
GPIO2	Disable/ Pull-up	Input/ Pull-up (Note2)	PWM1 Output	_	_	_	_	Open (Note1)	
GPIO3	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	PWM2 Output	SPI-DOUT Output	_	_	ADC1 Input	Open	
GPIO4	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	PWM3 Output	SPI-DIN Input	_	_	ADC2 Input	Open	
GPIO5	Disable/ Pull-up	Input/ Pull-up (Note3)	UART1-TX Output	SPI-DOUT Output	_	_	_	Open	
GPIO6	Disable/ Pull-up	Input/ Pull-up (Note3)	UART1-RX Input	SPI-DIN Input	_	_	_	Open	
GPIO7	Disable/ Pull-up	Input/ Pull-up	I2C-SCL Output	_	SPI-SCS Output	UART1-RTSX Output	_	Open	
GPIO8	Disable/ Pull-up	Input/ Pull-up	I2C-SDA I/O	_	SPI-SCLK Output	UART1-CTSX Input	_	Open	
GPIO9	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	_	_	_	_	ADC3 Input	Open	
GPIO10	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	_	_	_	_	ADC4 Input	Open	
GPIO11	Disable/ Pull-up	Input/ Pull-up	I2C-SCL Output	SPI-DOUT Output	_	_	_	Open	
GPIO12	Disable/ Pull-up	Input/ Pull-up	I2C-SDA I/O	SPI-DIN Input	_	_	_	Open	
GPIO13	Disable/ Pull-up	Input/ Pull-up	UART1-RTSX Output	32 kHz Output	_	_	_	Open	
GPIO14	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	UART1-CTSX Input	32 kHz Output	_	_	ADC5 Input	Open	
GPIO15	Disable/ Hi-Z	Disable/ Disconnection: Pull-up, Pull-down	WakeUp1 Input	_	_	_	_	Open	
GPIO25	Disable/ Pull-up	Input/ Pull-up	_	_	_	_	_	Open	

Note1: Handle with care because of using operation mode switching.

Note2: Except in User-App mode, it becomes Pull-down.

Note3: In the HCl mode, the pull-up / pull-down resistor is disconnected.



2.4. Power Supply Pins

Table 2-3 shows the attributes and descriptions of power supply pins for normal operations.

Table 2-3 Power supply pins

Pin name	Pin number	Attribute	Description
		Туре	
		VDD/GND	
			VDD/GND
VPGM	5	TEST	Test pin
		_	Please connect VPGM to GND.
VBAT	18	VBAT	Power supply pin for DCDC and sleep circuit.
		VDD	Connect the external power source for DCDC and LDO built into the IC.
LX	19	VBAT	DCDC output pin.
		VDD	Please connect to external inductor for DCDC.
VDDCORE1	14	_	DCDC for feedback input, analog circuit power supply pin.
		VDD	Please connect to external inductor for DCDC.
VDDCORE2	15	_	DCDC for feedback input, digital circuit power supply pin.
		VDD	Please connect to external inductor for DCDC.
VDDIO1	1	VDDIO	IO power supply
VDDIO2	23	VDD	Power supply pin for GPIO.
VDDIOFQ	27	VDDIOFQ	Flash ROM external capacitor connection pin.
VDDIOFQ	21	VDDIOFQ	It has been connected to the power supply of the internal flash ROM of the IC.
		VDD	As the LDO load capacitor, a capacitor of 0.1 µF or more should be
			connected at the operation temperature.
VSSA	8	Analog	GND pin for analog, this pin needs to be connected to GND.
VOOR		GND	GIVE PHILOT CHANGE, THE PHILICECUS TO BE CONTRICUED TO CHASE.
VSSRFIO	6	Analog	GND pin for RFIO, this pin needs to be connected to GND.
		GND	
VSSX	13	Analog	GND pin for OSC, this pin needs to be connected to GND.
		GND	
VSSDC	20	Digital	GND pin for DCDC, this pin needs to be connected to GND.
		GND	
VSSD	FIN	Digital	Die pad ground Fin. Connect the exposed Die Pad to GND because this pad
		GND	is digital ground as well.

3. System Configuration

3.1. Block Diagram

Figure 3-1 shows block diagram of TC3567C.

TC3567C is powered by single voltage between 1.8 V and 3.6 V, especially 2.0 V of power supply is required in accessing to the internal flash ROM and the booting process. The chip has built-in DCDC and LDO requiring external capacitors. It uses 26 MHz reference clock and 32.768 kHz sleep clock. External memory interface is SPI or I²C, and host CPU interface is UART.

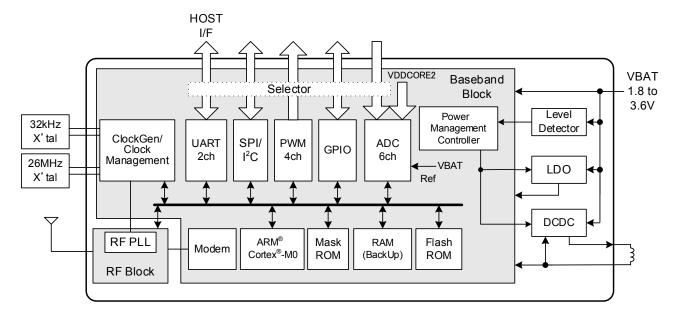


Figure 3-1 Example of TC3567C system configuration

3.2. Boot Sequence

The boot sequence of TC3567C is as shown below.

Depending on the pin state of GPIO1 at the time of reset release, it can be used to switch between User-App mode and HCI mode.

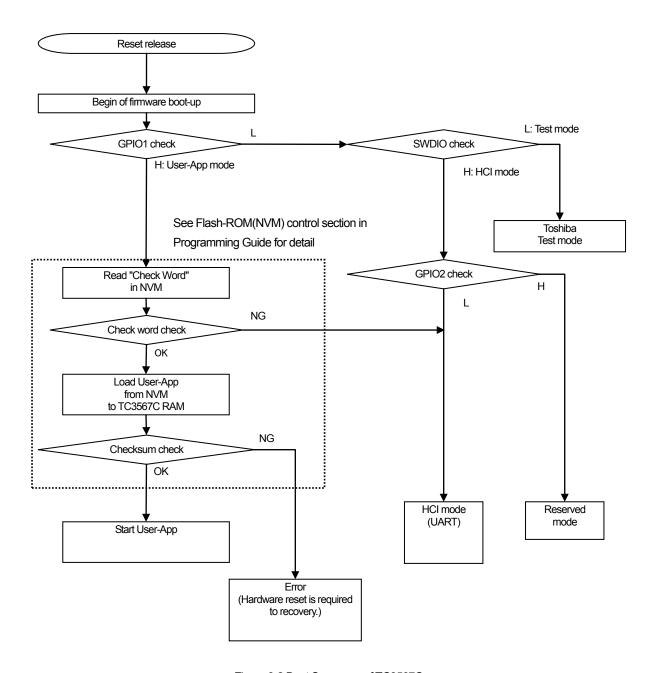


Figure 3-2 Boot Sequence of TC3567C

4. Hardware Interfaces

4.1. Reset Interface (Power up sequence)

4.1.1. Features

Reset interface has the following features.

- 2.0 to 3.6 V operation
- Level sensitive asynchronous reset (Low level: reset)

The reset signal should be at reset status (RESETX = Low) when the power is turned on. When the power supply has become over 2.0 V, to be disable the reset signal (RESETX = High). Then starts the X'tal oscillation after DCDC output has become stable If DCDC is used, or after each LDO output has reached its target voltage from VBAT supplying voltage. Then, an internal timer releases the internal reset after the X'tal oscillation has become stable.

4.1.2. Connection Example

Reset signal can be input by an RC time constant circuit or an asynchronous level sensitive reset IC. Figure 4-1 shows a connection example where TC3567C is power-supplied by an RC time constant circuit. Reset signal can be given by RC time constant circuit. Figure 4-2 shows the timings to reset and reset-release for the power supply.

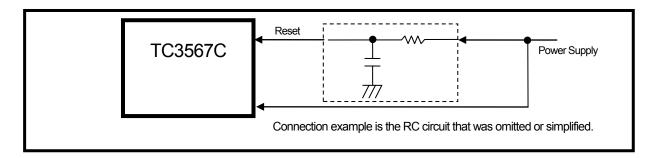


Figure 4-1 Reset signal connection example

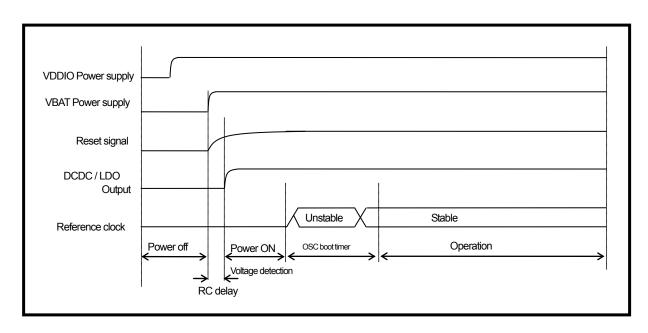


Figure 4-2 Power-on reset release sequence

4.2. UART Interface

4.2.1. Features

TC3567C UART interface has the following features.

- > 1.8 to 3.6 V operation
- Full-duplex start-stop synchronization data transfer (RX, TX, CTSX, RTSX)
- Two-wire start-stop synchronization data transfer (RX, TX) or four-wire start-stop synchronization data transfer (RX, TX, CTSX, RTSX) are available depending on the settings.
- > Start bit field (1 bit), data bit field (8 bit, LSB first), stop bit field (1 bit), no parity bit
- In HCI mode, UART TX/RX pins can be switched by commands.
- > Programmable baud rate: 9600 bps to 921.6 kbps.
- More than 3 characters are inserted between TX messages. Interval can be changed on the command.
- > Error detection (receiver timeout error, receiver over run error, receiver frame error)
- Host wake up function

TC3567C communicates commands, status, and data with a host CPU through UART interfaces. The UART interfaces are shared with GPIO pins, and during boot process after a reset, TC3567C firmware assigns UART functions to the GPIOs. The UART interfaces can operate at 1.8 to 3.6 V depending on the VDDIO power supply voltage. Sharing the power supply pin with other hardware interfaces, they cannot operate at a different voltage from the one other hardware interfaces operate at.

4.2.2. Connection Example

TC3567C UART can be connected with an UART interface on a host CPU. Figure 4-3 shows an example of two-wire start-stop synchronization data transfer connection with an external host CPU. Figure 4-4 shows the timing when UART is assigned to GPIO and activated.

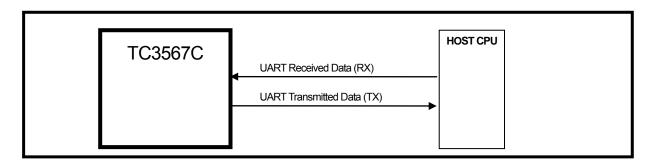


Figure 4-3 UART connection example

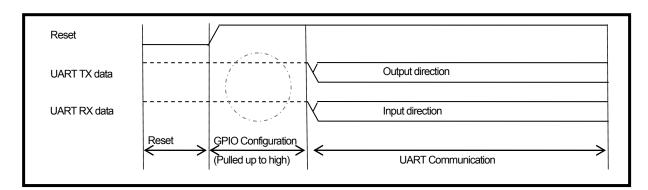


Figure 4-4 Timing for UART function assignment



4.2.3. Frame Format

TC3567C supports the following format:

Number of data bits: 8 bits (LSB first)
 Parity bit: no parity
 Stop bit: 1 stop bit

Stop bit: 1 stop bitFlow control: RTSX/CTSX

Figure 4-5 shows UART data frame.

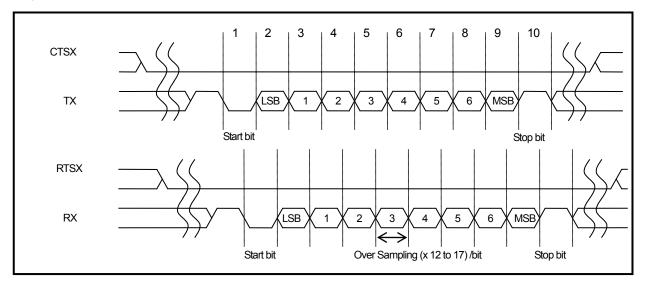


Figure 4-5 UART data frame

4.2.4. Flow Control Function

Hardware flow control is available when TC3567C UART interface is assigned to GPIO5 to GPIO8 (GPIO5, 6, 13, 14) as four-wire start-stop synchronization data transfer. Transmit flow control (CTSX) and receive flow control (RTSX). Figure 4-6 shows signals input and output direction.

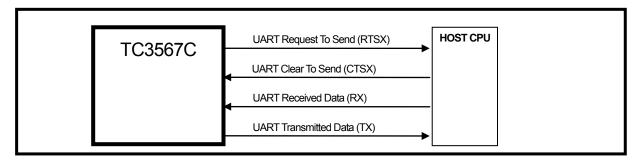


Figure 4-6 UART connection example

CTSX (Clear to Send) input signal is used for UART transmitting. Low input indicates the peer device (for example, the host in the Figure 4-6) is ready to receive data, and TC3567C sends data if it has data to transmit. On the other hand, TC3567C stops transmitting on the basis of UART unit frame when CTSX input is high.

RTSX (Request to Send) output signal is used for UART receiving. Low output indicates TC3567C is ready to receive data and requests data to the peer device. TC3567C outputs RTSX low when ready to receive data. When the UART becomes busy and cannot receive data, TC3567C outputs RTSX high, and stops UART communication on the basis of UART unit frame.

Response time of UART transmitting and receiving to flow control signals is between 1 frame to 4 frames depending on the baud rate and internal process status of frame.

TC3567CFSG

4.2.5. TX message spacing function

TC3567C spaces more than 12 time frames between different TX messages making less than 12 time frames between TX frames in a TX message when several TX frames belong to one TX message. Host CPU is able to know the boundaries between TX messages by measuring time frames between TX frames.

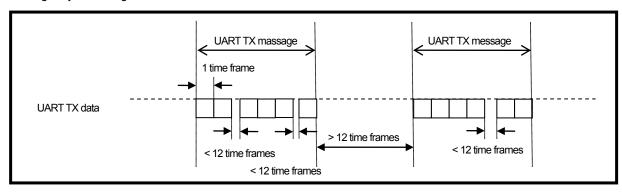


Figure 4-7 TX frames and TX messages

4.2.6. Error Detecting Functions

TC3567C UART interface has 3 kinds of error detecting functions.

- Receiver timeout error
- Receiver over run error
- Receiver frame error

Receiver timeout error detection judges an error if an UART RX message made from several RX frames has an RX frame interval longer than a certain value. The interval is counted by internal timer. Keep the interval between RX frames less than 12 time frames that belong to an RX message. For UART1, keep intervals between different RX messages more than 12 time frames. For example, 115200 bps has 0.087 ms for 1 frame, the interval between RX messages should be longer than 0.087 ms \times 12 = 1.04 ms. RX messages that has intervals less than 12 time frames gives an error because TC3567C sees them as one UART RX message. Interval of the received frame is the default in the 12 time frame, but it can be changed by the command.

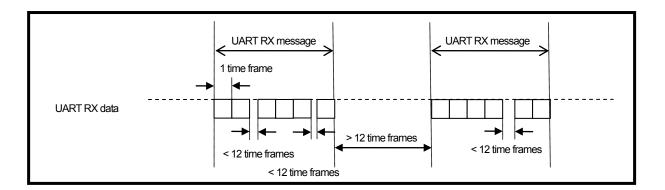


Figure 4-8 RX frames and RX messages

Receiver over run error judges if UART receive frame buffer internal TC3567C is overflowed. Normally, this overflow does not happen when the flow control mentioned in 4.2.4 is activated for data communication.

Receiver frame error judges if failing recognize the unit frame. A frame formation is judged as failure when its start bit is detected and the corresponding stop bit is detected as "0".

4.2.7. Host Wake up Function

TC3567C can wakes up its host before sending UART data to the host. This function is disabled by default, but can be assigned to GPIO by command. Host wake up time can be changed by command (10 ms by default).

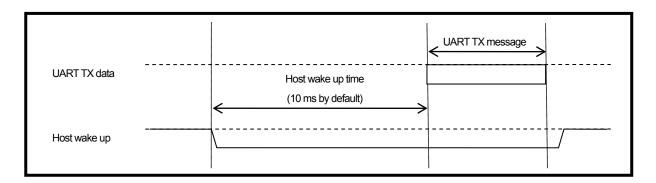


Figure 4-9 Host wake up

4.2.8. HCI mode

When TC3567C is used in the HCI mode, UART is the host interface to receive HCI commands. The Bluetooth[®] wireless performance can be tested in HCI mode by the measurement equipment which connects the UART directly.

4.2.8.1. HCI Reset

Sends a HCl reset command from the host, at least 150 μ s from the command complete event can be processed the following command successfully.

4.3. SPI Interface

4.3.1. Features

TC3567C has the following main features for a serial memory interface

Operation voltage: 1.8 to 3.6 V

SPI interface

> Chip select: 1 ch

Chip select polarity: Selectable: High-active and Low-active

Serial clock master operation: Polarity and phase are adjustable (4 combinations are selectable)

Serial clock frequency: 25 kHz to 6.5 MHz
 Serial data transfer mode: MSB-first, LSB-first

SPI interface can operate at 1.8 to 3.6 V depending on VDDIO, however, cannot operate at different voltage from ones other interfaces are operate at.

4.3.2. Connection Example

TC3567C SPI interface can be connected to serial EEPROMs and serial Flash-ROMs and has 1 chip select port. Figure 4-10 shows a connection example, where a serial Flash-ROM is connected to TC3567C SPI interface.

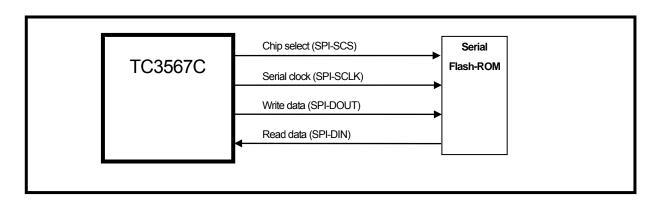


Figure 4-10 Connection example for serial Flash-ROM using SPI interface

4.3.3. Frame Format

When the SPI interface is connected to external ICs, the first 8 bit (X7 to X0) specifies the address and read or write mode. The command recognition code type and the address bit width should be determined by the external IC in use. For more information in detail, please refer to the technical documents for the external IC.

Figure 4-11 shows an example where 8-bit address is written and then 8-bit data is read. Figure 4-12 shows an example where 8-bit address is written and then 8-bit data is written.

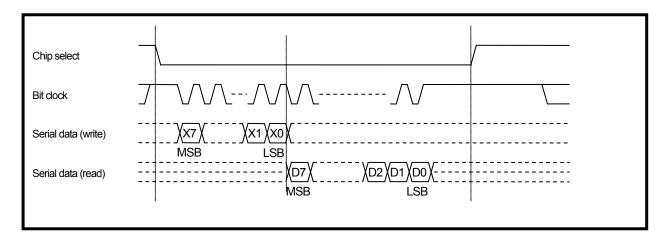


Figure 4-11 SPI format (single byte read)

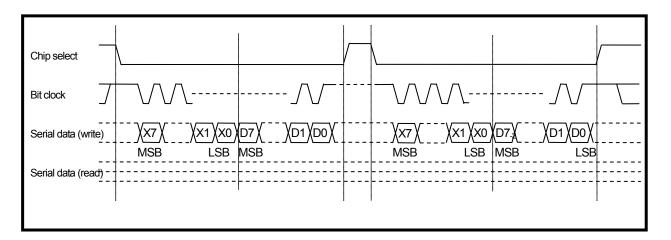


Figure 4-12 SPI format (single byte write)

4.4. I²C Interface

4.4.1. Features

I²C has the following main features for a serial interface.

Operation voltage: 1.8 to 3.6 V

▶ I²C Interface

Operation mode:
I²C bus master

Serial clock frequency: Standard mode (Max 100 kHz), Fast mode (Min 100 kHz to Max 400 kHz)

Output mode: Open-drain output, CMOS output

> Device address format: 7-bit address (10-bit address is not supported)

I²C interface can operate at 1.8 to 3.6 V depending on VDDIO, however, cannot operate at different voltage from ones other interfaces are operate at.

4.4.2. Connection Example

Figure 4-13 shows a connection example of a serial EEPROM using I^2C bus interface of the open-drain mode. External pull-up resistors (Rext) are necessary for both serial clock line and serial data line.

Figure 4-14 shows another connection example where I²C bus is in the CMOS output mode. Only the serial data line needs Rext because this line can be driven by neither TC3567C nor a serial EEPROM.

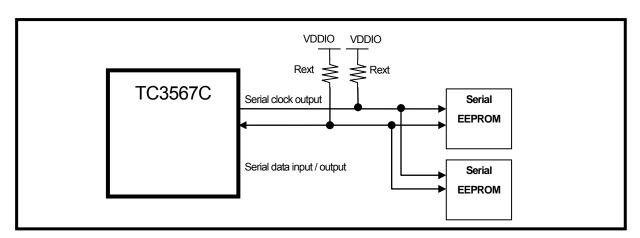


Figure 4-13 Connection example for serial EEPROM with I²C-bus interface (Open-drain output)

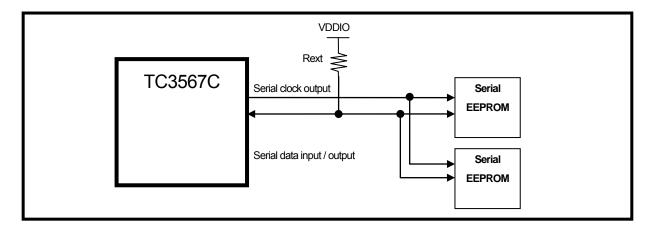


Figure 4-14 Connection example for serial EEPROM with I²C-bus interface (CMOS output)

4.4.3. Selection of External Pull-up Resistor Value

An external pull-up resistor value needs to be selected by the following equations in case of I^2C bus interface. Its maximum value is defined by equation (1), in which t_r is rise time of serial clock and data and C_b is I^2C bus capacity. Its minimum value is defined by equation (2), in which VDDIO is a supply voltage for TC3567C, V_{ol_max} is the maximum value of low level output voltage, and I_{ol} is the low level output current. Please set the pull-up resistor value between these lower and upper limits.

$$R_{\text{ext_max}} = \frac{t_r}{0.8473 \times C_b} \tag{1}$$

$$R_{\text{ext_min}} = \frac{VDDIO - V_{ol_max}}{I_{ol}}$$
 (2)

TC3567C supports I^2 C bus standard mode (Max 100 kHz) and I^2 C bus fast mode (Min 100 kHz to Max 400 kHz). The rise time t_r is 1000 ns for the standard mode and it is 300 ns for the fast mode. C_b can vary depending on the IC board and how it is implemented. Table 4-1 and Table 4-2 show examples when I^2 C bus capacity is 20 pF.

Table 4-1 External pull-up resistor value for I²C standard mode (Cb = 20 pF)

I ² C bus frequency		Max 100 kHz							
tr [ns]					1000				
Cb [pF]					20				
VDDIO [V]		1.8		3.0			3.6		
Vol_max [V]		0.3		0.4			0.4		
lol [mA]	1	2	4	1	2	4	1	2	4
Rext_min [kΩ]	1.50	1.50 0.75 0.38			2.60 1.30 0.65			1.60	0.80
Rext_max [kΩ]		59.01							

Table 4-2 External pull-up resistor value for l^2C fast mode (Cb = 20 pF)

I ² C bus frequency		Min 100 to Max 400 kHz							
tr [ns]					300				
Cb [pF]		20							
VDDIO [V]		1.8		3.0			3.6		
Vol_max [V]		0.3		0.4			0.4		
lol [mA]	1	2	4	1	2	4	1	2	4
Rext_min [k Ω]	1.50	1.50 0.75 0.38			1.30	0.65	3.20	1.60	0.80
Rext_max [kΩ]		17.70							

4.4.4. Frame Format

For I²C format, TC3567C first generates start condition. Then, it sends device recognition address (7 bit: [A6:A0]) and the first byte address ([B7:B0]) for the access target. Next, it goes for read or write sequence. For I²C, every data is sent as MSB first. How to specify the value and byte address of the device identification address, and it has been determined in accordance with the device to be connected. In order to be connected, it must match the device to be connected. For read operation, TC3567C returns to the serial memory either receive acknowledge bit (ACK) or receive not acknowledge bit (NACK) every time it receives one byte. For write operation, TC3567C receives either ACK or NACK from the serial memory every time it sends one byte. It can handle not only one byte but also several bytes in a row. TC3567C generates stop condition when it has finished all the read or write of data.

Figure 4-15 shows an example where TC3567C reads two-byte data. Figure 4-16 shows an example where TC3567C writes two-byte data. In these examples, gray texts and lines indicate signals that are given by the serial memory. For read operation, after having read the final byte data, TC3567C returns NACK with which the serial memory gets to know the completion of the read operation.

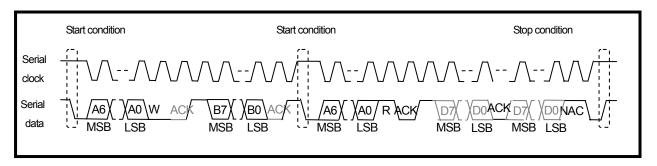


Figure 4-15 I²C format (Serial memory, read)

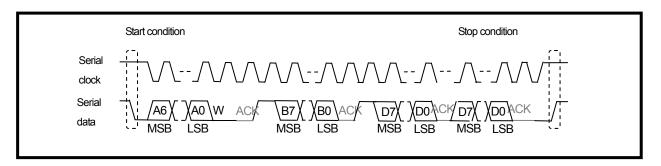


Figure 4-16 I²C format (Serial memory, write)

4.5. PWM Interface

TC3567C has a PWM interface that can be used for LED, buzzer control, etc.

The PWM interface has the following features.

- Arbitrary pulse generation function
- > It can select the source clock from 13 MHz and 32.768 kHz
- It has 12-bit clock division setting up to 1/4096: 8 Hz to 16.384 kHz (32.768 kHz), 3.17 kHz to 6.5 MHz (13 MHz)
- > The pulse output can be masked by the regular pattern whose period is one second with 50 ms unit width (Rhythm function).
- > It can generate an interrupt which is synchronized to the rhythm pattern period 1 s.
- > It can switch the pulse output to Low / High active
- It can adjust the duty cycle of the pulse output.

4.5.1. Pulse Generation Function

Figure 4-17 shows a brief explanation of the pulse generation. TC3567C can adjust output pulse frequency by changing its cycle. Also it can adjust on/off ratio by changing its duty.

The cycle (frequency) can be set from 8 Hz to 16.384 kHz for 32.768 kHz clock, and from 3.17 kHz to 6.5 MHz for 13 MHz clock. The duty can be set from 0% to 100%

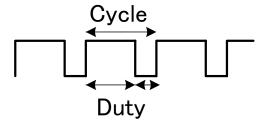


Figure 4-17 PWM pulse generation function

4.5.2. Rhythm Function (Output Masking)

Figure 4-18 shows the brief explanation of PWM rhythm function. In addition to the one for pulse generation, TC3567C has another timer that has $50 \text{ ms} \times 20 = 1 \text{ s}$ (rhythm counter). That timer has 20-bit register (pattern register), each bit corresponds to the rhythm counter that counts down in every 50 ms. When the pattern register is zero, the PWM output is masked to zero or one. Using this function, LED or buzzer can be on with 1 s periodical pattern

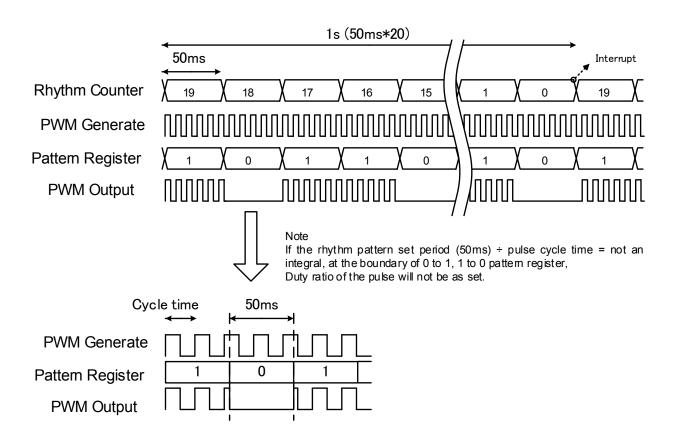


Figure 4-18 PWM Rhythm Function

4.6. ADC

4.6.1. Features

TC3567C has 6 ch of 10-bit ADCs for battery monitoring, analog inputs from external sensors, for example. The ADC has the following features.

- 5 ch for analog inputs Note: Analog inputs are shared with GPIO pins.
- > 1 ch for VBAT voltage monitor

Note: The reference input is internally connected to VBAT, and the analog input is to built-in VDDCORE2 output. Please refer to 4.6.2 for how to calculate voltage value.

Maximum conversion rate: 1 MS/s

4.6.2. Descriptions

The ADC has 10 bits conversion accuracy and can work for input voltages from 0 V to 3.6 V (VBAT). It has 6 ch of analog inputs, and the ch0 is connected to VDDCORE2 output, and the ch1 to ch5 are shared with GPIO pins.

When a battery is used as power source, the reference voltage can slide over time because the battery is connected as reference voltage. In that case, the VDDCORE2 output voltage connected to ch0 can be used as a reference voltage. The input voltage to ch1 to ch5 is converted by the reference voltage of ch0 and the converted value is used to calculate a correct digital value by the CPU. The following shows the conversion method of the input voltage.

Voltage A at time T can be calculated as follows

- (1) VDDCORE2 output voltage (VDDCORE2) on Ch0 should be converted by the ADC. The converted digital value is X.
- (2) The analog signal on Ch1 is converted and the converted digital value is Y.
- (3) When the absolute value of the analog signal on Ch1 is defined as Z(V), VDDCORE2(V)/Z(V) = X/Y. So,

$$Z(V) = VDDCORE2(V) \times Y/X$$

Calculation example:

Suppose ch0 (for ex. VDDCORE2 output is 1.2 V) is converted to 0x0188, and ch1 (measurement target) is converted to 0x0134, the absolute voltage at ch1 Z (V) is given by $1.2 \times 0x0188 / 0x0134 = 1.2 \times 392 / 308 = 1.527$ (V).

Figure 4-19 shows conceptual of voltage conversion.

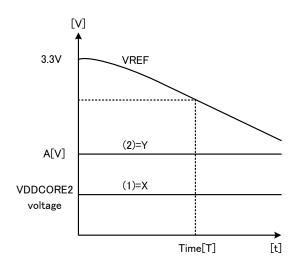


Figure 4-19 Voltage conversion concept

The ADC converts inputs from ch selected by register settings. When a conversion has finished, the CPU detects it by the interrupt or register polling, and then returns the results. The maximum sampling rate depends on software load on the CPU.

Note: The numerical values are expressed as follows.

Hexadecimal number: 0xABC

4.7. IC Reference Clock Interface

4.7.1. Features

TC3567C has the following features for IC reference clock interface.

Clock frequency: 26 MHz (please adjust the accuracy to < 50 ppm at the temperature in use)</p>

TC3567C doesn't require external feedback resistors and load capacitor because it has an internal feedback resistor and capacitor array. Please adjust capacitor array, based on the specification of the used oscillator and PCB layout and assembly.

4.7.2. Connection Example

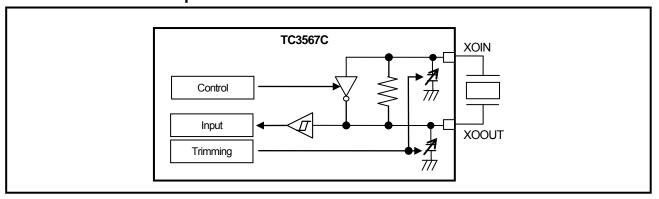


Figure 4-20 Crystal oscillator connection example

4.8. Sleep Clock Interface

TC3567C has the following features for sleep clock interface.

- Crystal oscillator can be connected.
- Clock frequency: 32.768 kHz (please adjust the frequency accuracy to less than or equal to ±500 ppm at the temperature in use.)

Crystal oscillator is connected between SLPXOIN pin and SLPXOOUT pin. TC3567C doesn't require external feedback resistors and load capacitor because it has an internal feedback resistor and capacitor array between SLPXOIN pin and SLPXOOUT pin. Please adjust capacitor array based on PCB layout and assembly if necessary within the range of the X'tal's specification. When an external oscillator is connected, connect it to SLPXOIN and SLPXOOUT should be connected to the GND. When oscillator is not used and do not supply a clock from the outside, this pin needs to be connected to the GND.

4.8.1. Sleep Clock Connection Example

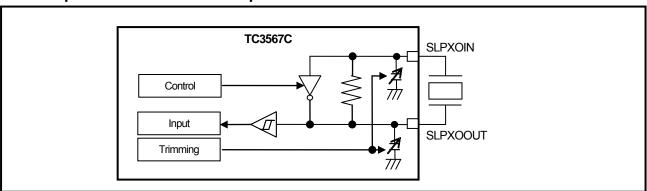


Figure 4-21 Crystal oscillator connection example

4.8.2. External Oscillator Connection Example

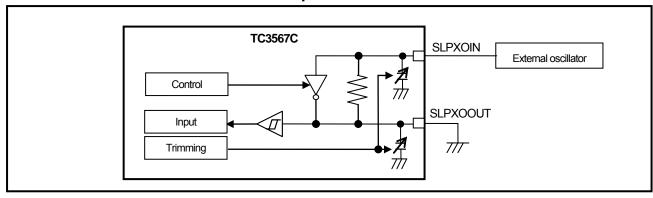


Figure 4-22 External oscillator connection example

5. Electric Characteristics

5.1. Absolute Maximum Ratings

Absolute maximum ratings must not be exceeded even for a moment. Voltages, currents, and temperatures that exceed the absolute maximum ratings can cause break-downs, degradations, and damages not only for ICs but also for other components and boards. Please make sure application designs not to exceed the absolute maximum ratings in any situation.

Table 5-1 Absolute maximum ratings (VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

Items	Cumbala	Rati	Units		
items	Symbols	Min	Max	UTILS	
Power supply	VBAT	0.3	-0.3 +3.9		
	VDDIO (Note1)	-0.3 +5.9			
Input voltage	VIN	-0.3	VDDIO + 0.3 (Note2)	V	
Output voltage	VOUT	-0.3	VDDIO + 0.3 (Note2)	V	
Input current	IIN	-10	+10	mA	
Input power	RFIO	_	+6	dBm	
Storage temperature	Tstg	-40	+125	°C	

Note1: Do not connect VBAT to GND while VDDIO is powered. Current from VDDIO to VBAT through IC may cause damages, break-downs, and degradations.

Note2: Please use VDDIO + 0.3 V not to exceed 3.9 V.

5.2. Operating Conditions

TC3567C can operate normally with proven quality under the operating ranges. Any diversion from the operating ranges may cause false operation. Thus, please make sure application design to comply these operating ranges.

Table 5-2 Operating conditions (VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

	Items	Symbols		Ratings		Units
	ileris	Symbols	Min	Тур.	Max	UTIILS
	VBAT Operating Voltage1 (Note1)	VBATopr1	1.60	3.00	3.60	V
	VBAT Operating Voltage2 (Note1)	VBATopr2	1.79	3.00	3.60	V
	VBAT Operating Voltage3 (Note2)	VBATopr3	2.00	3.00	3.60	V
Power supply	VDDIO Operating Voltage (Note3)	VDDIOopr	1.80	3.00	3.60	٧
	VDDIOFQ Output Voltage (Note3)	VDDIOFQ	_	1.7	_	V
	VDDCORE Voltage (Note3)	VDDCORE1/ VDDCORE2	_	1.2	_	V
RF	frequency	Fc	2400	_	2483.5	MHz
Clast	r fraguancias	Reference clock Fck	25.99870	26.00000	26.00130	MHz
Clock	r frequencies	Sleep clock fslclk	32.751616	32.768000	32.784384	kHz
Am	bient temp.	Ta	-40	+25	+85	°C

Note1: The low-voltage detection function is built in the VBAT pin. The IC operation is stop when the operating voltage falls to the minimum value of the VBAT operating voltage 1 (VBATopr1). The low-voltage detection voltage has a hysteresis in order not to start the IC repeatedly by the load variation after stopping. During voltage boosting, the internal CPU powers on when the operating voltage rises to the minimum value of the VBAT operating voltage 2 (VBATopr2). However, please pay attention that the minimum voltage of the VBAT operating voltage 3 (VBATopr3) is required for the reading and writing operation of the flash ROM as indicated in the Note 2.

Note2: For reading and writing operation to the flash ROM in the digital block, the power in the range of VBAT operating voltage 3 should be supplied. In the booting process, please release RESET after the voltage rises to the minimum value (2.0 V) because of accessing to the flash ROM to confirm the existence of applications. Moreover, in case of operating in the User-App mode or driving till the under voltage detection turns off the operation, please pay attention to the relation between RW operation to the flash ROM and the voltage.

Note3: Please refer to other documents (application note) for our connection examples.

Please do not input external power supply and do connect external capacitors to VDDIOFQ because they are supplied by the internal LDO.



5.3. DC electric characteristics

5.3.1. Current Consumption (Design value)

This section shows current consumption. When the operating temperature (Ta) is 25°C, and the operation of each power supply pin is in the recommendation connection state of our company, the current consumption is an average value.

Table 5-3 Current consumption (VBAT = VDDIO1 = VDDIO2 = 3.0 V, VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

Itomo	Cumbolo	Conditions	Pins		Ratings		Unit
Items	Symbols	Conditions	(Note) Min Typ. Max — 0.8 — — 2.4 — VBAT — 15.6 — — 3.3 — — 3.3 — d — 2.5 — d VBAT — 2.4 —				
Digital operation	IDD _{DIG} (Active1)	_		_	0.8	_	
Flash read	IDD _{RD} (Flash Read)	_		_	2.4	_	
Flash write	IDD _{WR} (Flash Write)	_	VBAT	_	15.6	_	mA
RX	IDD _{RX} (Active2)	_		_	3.3	_	
TX	IDD _{TX} (Active3)	Output Power= 0 dBm		_	3.3	_	
Low power mode With Connection	IDDS1 (Sleep)	26 MHz crystal oscillator disabled 32 kHz crystal oscillator enabled		_	2.5	_	
Low power mode Without Connection	IDDS2 (Backup)	26 MHz crystal oscillator disabled 32 kHz crystal oscillator enabled	VBAT	_	2.4	_	μА
Low power mode Without Connection	IDDS (Deep Sleep)	26 MHz crystal oscillator disabled 32 kHz crystal oscillator disabled		_	0.05	_	

Note: Power consumption for IO depends on its settings.

Table 5-4 shows DC electric characteristics for each pin under 25°C ambient temperature.

Table 5-4 DC Electric Characteristics (VBAT = VDDIO1 = VDDIO2 = 3.0 V, VSSD = VSSA = VSSRFIO = VSSDC = VSSX = 0 V)

		Con	dition	Measuring Pin		Rating		
Items	Symbols	I/F Voltage	Other Condition	(Note 1)	Min	Тур.	Max	Unit
High Level								
Input	VIH	3.0 V	LVCMOS	VDDIO	0.8×VDDIO	_	_	
Voltage								V
Low Level								•
Input	VIL	3.0 V	LVCMOS	VDDIO	_		0.2×VDDIO	
Voltage								
High Level			Pull-down Off		-10	_	10	
Input	IIH	VDDIO =	Dull days On		10		200	
Current		Input Voltage	Pull-down On	VDDIO	10		200	μА
Low Level		of each pin	Pull-up Off		-10	_	10	
Input	IIL		Pull-up On		-200		-10	
Current			Pull-up Off		-200	_	-10	
High Level								
Output	VOH	3.0 V	IOH = 1 mA	VDDIO	VDDIO-0.6	_	_	V
Voltage								
Low Level								
Output	VOL	3.0 V	IOL = 1 mA	VDDIO	_		0.4	V
Voltage								
External	VIH	3.0 V		SLPXOIN	0.8×VDDIO	_	_	V
32 kHz	SLPCLK	5.0 V		OLI AOII	0.0~ 1000			v
Clock Input level (Note2)	VIL SLPCLKL	3.0 V	_	SLPXOIN	_	_	0.2×VDDIO	V

Note 1: Please refer to Table 2-3 for power supply line for each pin.

Note 2: External oscillator is used for this case instead of crystal oscillator.

5.4. Built-in Regulator Characteristics

Table 5-5 Built-in regulator characteristics (VBAT = 1.8 to 3.6 V, VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

Items Symbols	C) male ala	Pin names and conditions		Units		
	Firmames and conditions	Min	Тур.	Max	Units	
Output voltages	ges Vout1	VDDCORE1/		1.2		\/
Output voltages		VDDCORE2		1.2	_	V

Table 5-6 Built-in regulator characteristics (VBAT = 1.8 to 3.6 V, VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

Items	Symbolo	Pin names and conditions		Lloito		
iterris	Symbols	Pirmames and conditions	Min	Тур.	Max	Units
Output voltages	Vout2	VDDIOFQ		1.7		V

5.5. ADC Characteristics

Table 5-7 ADC characteristics (VBAT = 1.8 to 3.6 V, VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

Items	Items Symbols Condition			Unit		
items			Min	Тур.	Max	Offic
Analog reference voltage	VREFH	_	1.8	3.0	3.6	V
Analog input voltage	VAIN	_	VSSD	_	VREFH	V

5.6. RF Characteristics (Design value)

The following conditions are applicable unless otherwise specified.

- ➤ Ta = 25°C
- ➤ VBAT = 3.0 V
- ➤ fx'tal = 26 MHz (Frequency accuracy is adjusted to ±2 ppm at normal temperature)
- ➤ PAOUT= 0 dBm

Table 5-8, Table 5-9 shows RF receiving characteristics and RF transmitting characteristics based on Bluetooth[®] Core Spec. V4.2 low energy.

About some the characteristics data here are design values.

Table 5-8 RF Characteristic

Test Item	Packet	bit	ala	Condition		Spec.		Unit
restitem	Packet	DIT	ch.	Condition	Min	Тур.	Max	Unit
Output Power	255 octets	PRBS9	0,12, 19,39	peak	_	_	Pavg+ 3 dB	dBm
	OCIDIS		19,59	average	_	0	_	
				-5 MHz	_	-60	-30	
	ns 255			-4 MHz	_	-55	-30	
				-3 MHz	_	-53	-30	
In-band Emissions		PRBS9	0,12,	-2 MHz	_	-48	-20	dBm
	octets	FNDOS	19,39	2 MHz	_	-50	-20	UDITI
				3 MHz	_	-53	-30	
				4 MHz	_	-56	-30	
				5 MHz	_	-60	-30	
		11110000		Δf1avg (11110000)	225	249.3	275	kHz
Modulation Characteristics	255 octets	10101010	0,12, 10.30	Δf2max (99.9 %)	99.9	100	_	%
Characteristics	ocieis	_	19,39	Δf2avg /Δf1avg	0.8	0.90	_	Ratio
Carrier frequency	255	10101010		average	_	4.4	_	kHz
offset (CFO)	octets	10101010		worst	-150	_	150	KΠZ
Carrier frequency drift	255 octets	10101010	0,12, 19,39	Absolute maximum	_	4.9	50	kHz
Carrier frequency drift Rate	255 octets	10101010		Absolute maximum	_	4.9	20	kHz/50 μs

Table 5-9 RF Characteristics

Test Item	Sub Item	Packet	bit	ch.	Condition	Min	Тур.	Max	Unit							
Rx Sensitivity	_	37 octets	_	0,12, 19,3	PER=30.8 % at 1500 packets with dirty	_	-93.5	_	dBm							
					<=7 MHz	_	-38 or less	_								
					-6 MHz	_	-32	_								
					-5 MHz	_	-26	_								
					-4 MHz	_	-30	_								
					-3 MHz	_	-32	_								
	PER=30.8 %		D wave:		-2 MHz	_	-35	_								
C/I and Receiver	at 1500	OFF antata	PRBS9	0,2,12,	-1 MHz	_	-2	_	٩D							
Selectivity Performance	packets	255 octets	U wave: GFSK	19,37, 39	0 MHz	_	8	_	dB							
CHOITIGHTCC	with dirty		PRBS15	55	1 MHz — -2	-2	_									
					2 MHz	_	-30	_								
					3 MHz	_	-38	_								
					4 MHz	_	-40	_								
					5 MHz	_	-44	_								
					=> 6 MHz	_	-38 or less	_								
					30-2000 MHz	-30	_	_								
Blocking		055 1.1	D wave: PRBS9	PRBS9	40	2003-2399 MHz	-35	_	_							
Performance	_	255 octets				U wave: CW							12	2484-2997 MHz	-35	_
			O wave. Ovv		3000 M-12.75 GHz	-30	_	_								
			f1=-50 dBm with		-4 MHz											
Intermodulation Performance	1500 packets	f2=-50 dBm	0,12, 19,39	+4 MHz	30.8	0	_	%								
Maximum input signal level	PER	255 octets	PRBS9	0,12, 19,39	-10 dBm	30.8	0	_	%							
PER Report Integrity	PER	255 octets	PRBS9	0,12, 19,39	-30 dBm	50	50	65.4	%							

Note: C/I characteristic and blocking characteristic has the relief specs of the logo attestation test of Bluetooth[®] maybe applied. The blocking characteristic measures D wave as 12 ch.

5.7. AC Interface Characteristics (Design value)

5.7.1. UART Interface

Table 5-10 UART Interface AC characteristics

Symbols	Items	Min	Тур.	Max	Unit
tCLDTDLY	Transmit Data ON from CTSX Low level	192	_	_	ns
tCHDTDLY	Transmit Data OFF from CTSX High level	_	_	2	byte
tRLDTDLY	Received Data ON from RTSX Low level	0			ns
tRHDTDLY	Received Data OFF from RTSX High level	_	_	8	byte

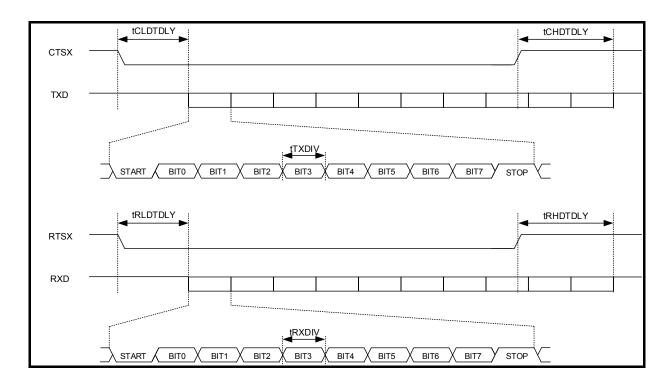


Figure 5-1 UART Interface Timing Diagram

5.7.2. I²C Interface 5.7.2.1. Normal Mode

Table 5-11 I²C Interface Normal mode AC Characteristics

Symbols	Items	Min	Тур.	Max	Unit
tDATS	Data set-up time	250	_	_	ns
tDATH	Data hold time	300	_	_	ns
tDATVD	Data validity period	_	_	3450	ns
tACKVD	ACK validity period	_	_	3450	ns
tSTAS	Restart condition set-up time	4700	_	_	ns
tSTAH	Restart condition hold time	4000	_	_	ns
tSTOS	Stop condition set-up time	4000	_	_	ns
tBUF	Bus open period from stop condition to start condition	4700	_	_	ns
tr	Rise up time	_	_	1000	ns
tf	Fall down time	_	_	300	ns
tHIGH	Serial clock period of High	4000		_	ns
tLOW	Serial clock period of Low	4700		1	ns
Cb	Bus load capacitance			400	pF

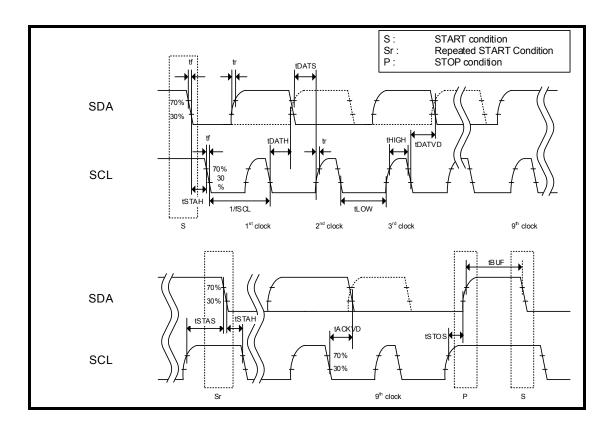


Figure 5-2 l^2C Interface Normal mode Timing diagram

5.7.2.2. Fast mode

Table 5-12 I²C Interface Fast mode AC Characteristics

Symbols	Items	Min	Тур.	Max	Unit
tDATS	Data set-up time	100	_	_	ns
tDATH	Data hold time	300	_	_	ns
tDATVD	Datavalidity period	_	_	900	ns
tACKVD	ACKvalidity period	_	_	900	ns
tSTAS	Restart condition set-up time	600	_	_	ns
tSTAH	Restart condition hold time	600	_	_	ns
tSTOS	Stop condition set-up time	600	_	_	ns
tBUF	Bus open period from stop condition to start condition	1300	_	_	ns
tr	Rise up time	20 + 0.1Cb	_	300	ns
tf	Fall down time	20 + 0.1Cb	_	300	ns
tSP	Spike pulse width that can be removed	0	_	50	ns
tHIGH	Serial clock period of High	_	1423	_	ns
tLOW	Serial clock period of Low	_	1423	_	ns
Cb	Bus load capacitance	_	_	400	pF

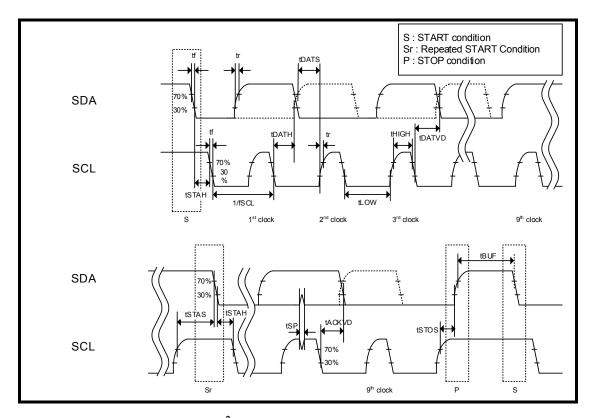


Figure 5-3 I²C Interface Fast mode Timing diagram



5.7.3. SPI Interface

Table 5-13 SPI Interface

Symbols	Items	Min	Тур.	Max	Unit
tSPICLKCYC	SPI clock cycle	154	_	_	ns
tSPICLKHPW	SPI clock high pulse width	77			ns
tSPICLKLPW	SPI clock low pulse width	77	_	_	ns
tSPICSS	SPI chip select setup time	38	_	_	ns
tSPICSH	SPI chip select hold time	77	_	_	ns
tSPIIW	SPI transfer idle pulse width	54	_	_	ns
tSPIAS	SPI address setup time	38	_	_	ns
tSPIAH	SPI address hold time	77			ns
tSPIDS	SPI data setup time	38			ns
tSPIDH	SPI data hold time	77	_	_	ns

Note: SPI Interface operates on the basis of 1/n frequency of half the frequency of ARM® Cortex®-M0 core clock (6.5 MHz for 13 MHz core clock)

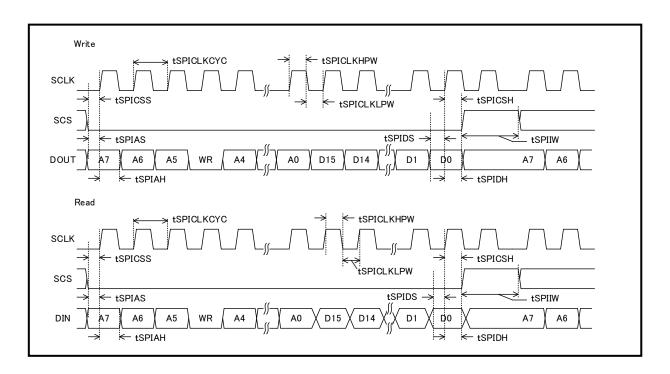


Figure 5-4 SPI Interface timing diagram

5.8. Characteristics of Flash-ROM block

Table 5-14 Characteristics of Flash-ROM block (VBAT=2.0 to 3.6 V, VSSA = VSSRFIO = VSSDC = VSSD = VSSX = 0 V)

Item	Symbol	Condition		Ratings		Unit
item	Symbol	Condition	Min	Тур.	Max	Offic
Number of times of		Ta=25°C	10 ⁵			timos
erase and program	_	1a-25 C	10	_	_	times

6. System Configuration Example

An example of system configuration is shown in the following figures.

6.1. In HCI mode

- Host interface=UART and 26 MHz Reference Clock= XOSC Connection.
- XOSC (32.768 kHz) of the dotted line enclosure is unnecessary when the external input (HOST common use) is chosen.
- GPIO and SWD of connection is the connection example of when not in use.

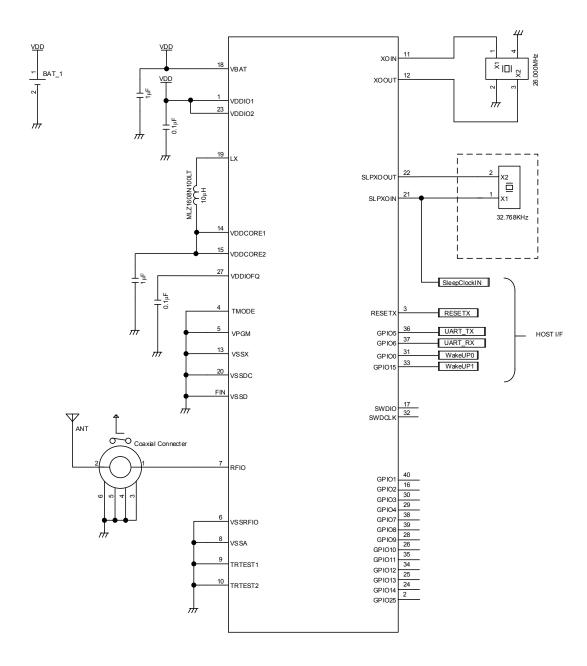


Figure 6-1 Example of TC3567CFSG system configuration (HCI mode)

6.2. In User-App mode

- XOSC (32.768 kHz) of the dotted line enclosure is unnecessary when the external input (HOST common use) is chosen.
- GPIO and SWD of connection is the connection example of when not in use.

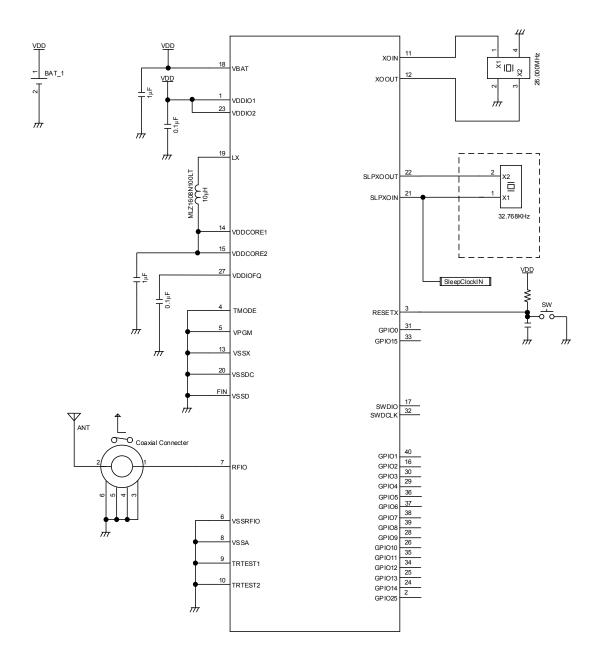
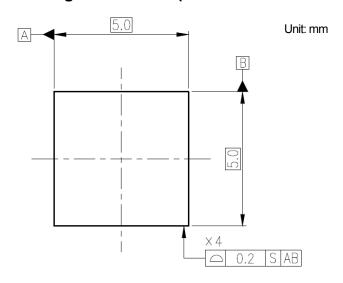
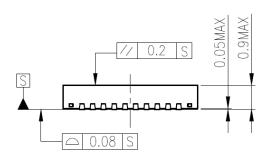


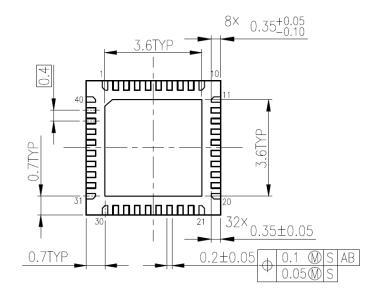
Figure 6-2 Example of TC3567CFSG system configuration (User-App mode)

7. Package outline

7.1. Outline dimensional drawing TC3567CFSG (P-VQFN40-0505-0.40-005/F01)







Weight: 0.068 g (Typ.)

Figure 7-1 Package outline (P-VQFN40-0505-0.40-005/F01)

RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY
 HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN
 LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific
 applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in
 the aerospace industry, medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment,
 equipment used to control combustions or explosions, safety devices, elevators and escalators, devices related to electric power, and equipment used
 in finance-related fields. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details,
 please contact your TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR
 PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING
 WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT
 LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY
 AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION,
 INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF
 INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use
 Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation,
 the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF
 NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.